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Electronic Devices And Circuits I Electron Devices and Circuits Profiles of Drug Substances, Excipients, and Related Methodology Complementarity and Variational Inequalities in Electronics Operations Research, Engineering, and Cyber Security Electronic Circuits Kashmir: Behind the Vale Nanoscale Materials and Devices for Electronics, Photonics and Solar Energy India Who's who Analog Electronic Circuits Citizen and Public Administration Basic Electronics Interim Measures in International Commercial Arbitration Indian Science Abstracts Electron Devices Guide to Indian Periodical Literature Objective General English Russian Journal of Physical Chemistry Sainik Samachar Control System Engineering National Symposium on Agricultural Research and Development Since Independence, Held at New Delhi, March 4-12, 1973 Indian Book Industry Productivity THE INDIAN LISTENER The Constitution of India The Indian Police Journal Report of the Secondary Education Commission, October 1952-June 1953 ISAE Directory The American Mathematical Monthly Report of the Secondary Education Commission, October, 1952-June, 1953 Elements Of Electronics Engineering The Civil List of Indian Administrative Service Bibliography of Agriculture Index to Theses Accepted for Higher Degrees in the Universities of Great Britain and Ireland The Encyclopedia of Film Annual review of biochemical and allied research in India Report, October 1952-June 1953 Annual Review of Biochemical and Allied Research in India Theses and Dissertations Accepted for Higher Degrees Soviet Physics

The book covers all the aspects of theory, analysis, and design of Electronic Circuits for the undergraduate course. It provides all the essential information required to understand the operation and perform the analysis and design of a wide range of electronic circuits, including MOSFET as a switching and amplifier circuits, feedback amplifiers, oscillators, voltage regulators, operational amplifiers and its applications, DAC, ADC, and Phase-Locked Loop. The book is divided into four parts. The first part focuses on the fundamental concepts of MOSFET, MOSFET construction, characteristics, and circuits - as a switch, as a resistor/diode, as an amplifier, and current sink and source circuits. The second part focuses on the analysis of voltage-series and current-series feedback amplifiers. It also explains the Barkhausen criterion for oscillation and incorporates the detailed analysis of Wien bridge and phase-shift oscillators. The third part is dedicated to the basics of op-amp and a discussion of a variety of its applications. The fourth part focuses on the V to I and I to V Converters, DAC and ADC, and Phase-Locked Loop. The book uses straightforward and lucid language to explain each topic. The book provides the logical method of describing the various complicated issues and stepwise methods to make understanding easy. The variety of solved examples is the feature of this book. The book explains the subject's philosophy, which makes understanding the concepts evident and makes the subject more interesting. Diode CircuitsDiode resistance, Diode equivalent circuits, Transition and diffusion capacitance, Reverse recovery time, Load line analysis, Rectifiers, Clippers and clampers.Transistor BiasingOperating point, Fixed bias circuits, Emitter stabilized

biased circuits, Voltage divider biased, D.C. bias with voltage feedback, Miscellaneous bias configurations, Design operations, Transistor switching networks, PNP transistors, Bias stabilization.Transistor at Low FrequenciesBJT transistor modeling, Hybrid equivalent model, CE fixed bias configuration, Voltage divider bias, Emitter follower, CB configuration, Collector feedback configuration, Hybrid equivalent model.Transistor Frequency ResponseGeneral frequency considerations, Low frequency response, Miller effect capacitance, High frequency response, Multistage frequency effects.General Amplifiers Cascade connections, Cascode connections, Darlington connections.Feedback Amplifier Feedback concept, Feedback connections type, Practical feedback circuits.Power AmplifiersDefinitions and amplifier types, Series fed class A amplifier, Transformer coupled class A amplifiers, Class B amplifier operations, Class B amplifier circuits, Amplifier distortions.OscillatorsOscillator operation, Phase shift oscillator, Wienbridge oscillator, Tuned oscillator circuits,, Crystal oscillator.FET AmplifiersFET small signal model, Biasing of FET, Common drain common gate configurations, MOSFETs, FET amplifier networks. This book presents research dedicated to solving scientific and technological problems in many areas of electronics, photonics and renewable energy. Progress in information and renewable energy technologies requires miniaturization of devices and reduction of costs, energy and material consumption. The latest generation of electronic devices is now approaching nanometer scale dimensions; new materials are being introduced into electronics manufacturing at an unprecedented rate; and alternative technologies to mainstream CMOS are evolving. The low cost of natural energy sources have created economic barriers to the development of alternative and more efficient solar energy systems, fuel cells and batteries. Nanotechnology is widely accepted as a source of potential solutions in securing future progress for information and energy technologies. Nanoscale Materials and Devices for Electronics, Photonics and Solar Energy features chapters that cover the following areas: atomic scale materials design, bio- and molecular electronics, high frequency electronics, fabrication of nanodevices, magnetic materials and spintronics, materials and processes for integrated and subwave optoelectronics, nanoCMOS, new materials for FETs and other devices, nanoelectronics system architecture, nano optics and lasers, non-silicon materials and devices, chemical and biosensors,quantum effects in devices, nano science and technology applications in the development of novel solar energy devices, and fuel cells and batteries. Semiconductor Diodes Classification of materials as insulator, Conductors and semiconductors, Types of semiconductors-intrinsic and extrinsic semiconductors, P-type and N-type, Majority and minority charge carriers, Drift current. The PN junction, Formation of depletion layer, Junction voltage, Effect of temperature on junction voltage, Forward and reverse biased PN junction. Reverse saturation current, V-I characteristics. Junction breakdown, Zener and avalanche breakdown, Junction capacitance and equivalent circuit. PN junction diode, V-I characteristics, Diode parameters, Applications, Diode ratings or specifications, Ideal diode and real diode, Introduction to zener diode.Bipolar Junction Transistor Introduction, Emitter, Base and collector of transistor, Transistor construction and biasing. Transistor circuit configurations, Common base, Common emitter, Common collector, Leakage current and thermal runaway.Field Effect Transistor Introduction, Symbol, Classification of FET, Basic construction of JFET, Opens operation and characteristics, MOSFET, Depletion and enhancement type MOSFET, Construction, Working. FET applications.Opto and Power Devices Introduction, Wavelength and frequency, Spectral response of human eye, LED, Photo emissive devices, Photo diode.UJT, SCR, TRIAC, DIAC, SCSConstruction, Parameters, Characteristics, Operation and applications.Operational Amplifiers and Power Supplies Ideal operational amplifier. Inverting

and non-inverting amplifier, Difference amplifier. Ground concept, Summing amplifier, Voltage follower.DC Power Supplies Introduction, Unregulated and regulated power supply, Rectifiers, Regulation, Zener diode shunt regulator, Transistor series voltage regulator. Voltage multipliers, Complete power supply.Cathode Ray OscilloscopeIntroduction, Cathode ray tube, Theory and construction, Applications.Electronic InstrumentsElectronic voltmeters, Differential amplifiers, DC voltmeters, Electronic multimeters.Logic Circuits Binary numbers, Conversion of decimal numbers to binary numbers. HEX and OCTAL numbers, Conversion to binary form, AND, OR, NOR, NAND and all logic gates, Symbols and truth table each case. Mathematical methods and theories with interdisciplinary applications are presented in this book. The eighteen contributions presented in this Work have been written by eminent scientists; a few papers are based on talks which took place at the International Conference at the Hellenic Artillery School in May 2015. Each paper evaluates possible solutions to long-standing problems such as the solvability of the direct electromagnetic scattering problem, geometric approaches to cyber security, ellipsoid targeting with overlap, non-equilibrium solutions of dynamic networks, measuring ballistic dispersion, elliptic regularity theory for the numerical solution of variational problems, approximation theory for polynomials on the real line and the unit circle, complementarity and variational inequalities in electronics, new two-slope parameterized achievement scalarizing functions for nonlinear multiobjective optimization, and strong and weak convexity of closed sets in a Hilbert space. /divGraduate students, scientists, engineers and researchers in pure and applied mathematical sciences, operations research, engineering, and cyber security will find the interdisciplinary scientific perspectives useful to their overall understanding and further research. Study of Electronic Materials and ComponentsClassification of materials based on bandgaps; Types of resistors-fixed, variable and precision etc. like carbon film, metal film, wire wound, cermets, Their standard values specifications and applications, Classification of capacitors based on dielectrics, Standard values, Specifications and applications of capacitors, Types of capacitors-electrolytic, ceramic, paper, mica, tantalum, plastic film etc. Study of different core materials depending on rage of frequencies for inductors and transformers; semiconductor materials, Si, Ge, AIII - BV compounds their properties.Semiconductor PhysicsElectrical properties of Ge and Si materials like intrinsic concentration, mobility, conductivity, energy gap, etc. Law of mass action, Generation and recombination of free charges (Holes/electrons). Diffusion phenomenon, Concentration gradient, Einstein relationship, Volt equivalent of temperature, Total current (drift and diffusion) potential variation within continuous and step graded semiconductor, i.e. p-n junction.Semiconductor Diode CharacteristicsCurrent components in forward biased / reverse biased p-n junction diode; cut-in voltage, Reverse saturation current, Derivation of V/I characteristics (logarithmic) equation of diode, Temperature dependence of diode characteristics, Concepts and significance of expressions of transition and diffusion capacitance, Junction diode switching times.Semiconductor Diode as Circuit Elementp-n junction as rectifier, Half-wave, Full-wave and bridge rectifier with and without capacitor filter, Other types of filters-choke input and L section filters, Parameters like ripple factor, Efficiency, TUF, PIV, IFmax, Isurage, etc. Derivations of ripple factor for L, C and L section filter, Bleeder resistor, Calculations for bridge rectifier with C filter for specified load voltage / current and ripple. Diode as a waveshaping element in clipping and clamping circuits, Voltage multipliers.BJT-Characteristics, Biasing Circuits and Bias StabilityBJT as a two-port device, Configurations of BJT (CE/CB/CC), Input-output and transfer characteristics in all three configurations with relevant V-I expressions and definitions of d.c. current gains, Concept of load line and Q point with active, Cut-off and saturation regions of operations of BJT. Early

effect, Punch through effect, Fixed collector feedback and self bias circuits for CE transistor, Definitions of stability factors for CE transistor and their derivations for above circuits; bias stabilization and compensation techniques, Condition to avoid thermal runaway. Absolute maximum rating of BJT as referred to datasheets.BJT as Small Signal LF AmplifierSmall signal LF-h parameter model in CE/CB/CC configuration; concept of A.C. equivalent circuit of single stage amplifier need of coupling and bypass capacitors; analysis CE/CB/CC amplifier for Ai, Av, Ri and Ro in terms of h-parameters; simplified h-parameter model; effect of biasing and source resistance on performance on single stage amplifier, Concept of frequency response.Field Effect TransistorConstruction of p-channel and n-channel JFET/D-MOSFET/E-MOSFET; output and transfer characteristics of each with definitions of parameters like gm, rd and m ; biasing techniques for all types, Small signal LF model of FET; analysis of CS/CD/CG amplifier for voltage gain and input-output impedance; comparison of BJT/JFET and MOSFET frequency response for FET amplifier. Absolute maximum rating/specification of FET as referred to datasheet.Special Semiconductor DevicesConstruction, Principle of operation; functional description with characteristics of each of the following devices; LED, Photo-diode, Photo-transistor, Photo-conductive cell, Photo-voltaic cell, Opto-isolator/coupler, LCD; applications of each. The Indian Listener (fortnightly programme journal of AIR in English) published by The Indian State Broadcasting Service,Bombay ,started on 22 December, 1935 and was the successor to the Indian Radio Times in english, which was published beginning in July 16 of 1927. From 22 August ,1937 onwards, it was published by All India Radio,New Delhi.In 1950,it was turned into a weekly journal. Later,The Indian listener became "Akashvani" in January 5, 1958. It was made a fortnightly again on July 1,1983. It used to serve the listener as a bradshaw of broadcasting ,and give listener the useful information in an interesting manner about programmes,who writes them,take part in them and produce them along with photographs of performing artists. It also contains the information of major changes in the policy and service of the organisation. NAME OF THE JOURNAL: The Indian Listener LANGUAGE OF THE JOURNAL: English DATE,MONTH & YEAR OF PUBLICATION: 22-04-1949 PERIODICITY OF THE JOURNAL: Fortnightly NUMBER OF PAGES: 100 VOLUME NUMBER: Vol. XIV, No. 9 BROADCAST PROGRAMME SCHEDULE PUBLISHED(PAGE NOS): 13-14, 17-91, 93-94 ARTICLE: 1. Industrial Well-being 2. Higher Education AUTHOR: 1. Dr. N.S.N. Sastry 2. Rev. Fr. T.N. Siqueira KEYWORDS: 1. Industrial happiness and worker psychology, Industrial science and happiness, Mass production and worker satisfaction 2. University education, Knowledge and society, Commonwealth Conference of Vice-chancellors Document ID: INL-1948-49 (D-J) Vol-I (09) Includes section "Recent publications." Profiles of Drug Substances, Excipients, and Related Methodology, Volume 44, presents comprehensive reviews of drug substances and additional materials, with critical review chapters that summarize information related to the characterization of drug substances and excipients. The series encompasses review articles, with this release focusing on Cefpodoxime proxetil, Levetiracetam, Paclitaxel, Sorafenib, Sucrose octaacetate, Thiouracil, Topiramate, Spectrophotometric analysis, and Cocrystal Systems of Pharmaceutical Interest: 2012-2014. Contains contributions from leading authorities Informs and updates on all the latest developments in the field of drug substances, excipients and methodologies Interim measures by courts as well as tribunals are often critical to succeed in arbitration proceedings and to effectively safeguard the rights of parties pending the final adjudication of their dispute. This important book comprises a comprehensive review of interim measures in international commercial arbitration granted by courts and tribunals across jurisdictions that have adopted the UNCITRAL Model Law to

critically assess the practical fault lines in the Indian arbitration regime. The book provides an in-depth analysis of the following: all reported judgments of the Indian Supreme Court and the High Courts from 1993 to 2022 on issues concerning interim measures; practical application of the UNCITRAL Model Law (and the revisions in 2006) by national arbitration statutes of over 80 jurisdictions with respect to interim measures; comparative practice and jurisprudence on interim measures in international commercial arbitration; rules of major arbitral institutions on the power and scope of interim measures granted by tribunals; detailed analysis of different types of interim measures, including anti-suit, anti-arbitration injunctions, security for costs, and interim measures in aid of foreign-seated arbitrations, the standards to be applied, and the burden of proof to be demonstrated for each type of measure; and issues of enforcement of interim measures in domestic, international, and foreign seated arbitrations. The current position of law in India and the problems plaguing the country's Arbitration and Conciliation Act 1996 (IAA), as amended in 2015 with respect to interim measures, are brought into direct comparison with other Model Law jurisdictions, offering an analysis of case laws, practical insights and cogent suggestions based on best practices that can be adopted by parties and tribunals. The Appendices provide a detailed list of statutory provisions of countries that have adopted the Model Law along with rules of major arbitral institutions on interim measures. The author not only describes the current position of law in India and other Model Law jurisdictions on interim measures but also reveals a comprehensive understanding of the requests for interim measures, and their enforcement in domestic, international, and foreign seated arbitrations. This book engages in a comprehensive and clear discussion on the fine line between court assistance and court intervention, especially in the case of interim measures and suggests draft provisions that India and other jurisdictions can adopt in order to align with the 2006 revisions to the Model Law to foster certainty, predictability, and efficiency in case of interim measures in international commercial arbitration. A collection for laypersons and experts alike, this authoritative work includes biographies of the stars, producers, directors, writers, technical information, and more The book is written for an undergraduate course on the Feedback Control Systems. It provides comprehensive explanation of theory and practice of control system engineering. It elaborates various aspects of time domain and frequency domain analysis and design of control systems. Each chapter starts with the background of the topic. Then it gives the conceptual knowledge about the topic dividing it in various sections and subsections. Each chapter provides the detailed explanation of the topic, practical examples and variety of solved problems. The explanations are given using very simple and lucid language. All the chapters are arranged in a specific sequence which helps to build the understanding of the subject in a logical fashion. The book starts with explaining the various types of control systems. Then it explains how to obtain the mathematical models of various types of systems such as electrical, mechanical, thermal and liquid level systems. Then the book includes good coverage of the block diagram and signal flow graph methods of representing the various systems and the reduction methods to obtain simple system from the analysis point of view. The book further illustrates the steady state and transient analysis of control systems. The book covers the fundamental knowledge of controllers used in practice to optimize the performance of the systems. The book emphasizes the detailed analysis of second order systems as these systems are common in practice and higher order systems can be approximated as second order systems. The book teaches the concept of stability and time domain stability analysis using Routh-Hurwitz method and root locus method. It further explains the fundamentals of frequency domain analysis of the systems including co-relation between time domain and frequency domain. The book gives very simple techniques for stability analysis

of the systems in the frequency domain, using Bode plot, Polar plot and Nyquist plot methods. It also explores the concepts of compensation and design of the control systems in time domain and frequency domain. The classical approach loses the importance of initial conditions in the systems. Thus, the book provides the detailed explanation of modern approach of analysis which is the state variable analysis of the systems including methods of finding the state transition matrix, solution of state equation and the concepts of controllability and observability. The variety of solved examples is the feature of this book which helps to inculcate the knowledge of the design and analysis of the control systems in the students. The book explains the philosophy of the subject which makes the understanding of the concepts very clear and makes the subject more interesting. The book covers all the aspects of theory, analysis, and design of Electron Devices and Circuits for the undergraduate course. The concepts of p-n junction devices, BJT, JFET, MOSFET, electronic devices including UJT, thyristors, IGBT, Amplifier circuits-BJT, JFET and MOSFET amplifiers, multistage and differential amplifiers, feedback amplifiers, and oscillators are explained comprehensively. The book explains various p-n junction devices, including diode, LED, laser diode, Zener diode, and Zener diode regulator. The different types of rectifiers are explained in support. The book covers the construction, operation, and characteristics of BJT, JFET, MOSFET, UJT, Thyristors - SCR, Diac and Triac, and IGBT. It explains the biasing of BJT, JFET, and MOSFET amplifiers, basic BJT, JFET, and MOSFET amplifiers with h-parameters and r-parameters equivalent circuits, multistage amplifiers, differential amplifiers, BiCMOS amplifier, single tuned amplifiers, neutralization methods, power amplifiers, and frequency response. Finally, the book incorporates a detailed discussion of the analysis of the current series, voltage series, current shunt, and voltage shunt feedback amplifiers. The book also includes the discussion of the Barkhausen criterion for oscillations and the detailed analysis of various oscillator circuits, including RC phase shift, Wien bridge, Hartley, Colpitt‘s, Clapp, and crystal oscillators. The book uses straightforward and lucid language to explain each topic. The book provides the logical method of describing the various complicated issues and stepwise methods to make understanding easy. The variety of solved examples is the feature of this book. The book explains the subject's philosophy, which makes understanding the concepts evident and makes the subject more interesting. Complementarity and Variational Inequalities in Electronics evaluates the main mathematical models relevant to the study of electrical network problems involving devices. The book focuses on complementarity problems, variational inequalities and non-regular dynamical systems which are well-known for their applications in mechanics and economics, but rarely target electrical applications. The book uses these tools to review the qualitative properties of devices, including slicers, amplitude selectors, sampling gates, operational amplifiers, and four-diode bridge full-wave rectifiers. Users will find demonstrations on how to compute optimized output signal relevant to potentially superior applications. In addition, the book describes how to determine the stationary points of dynamical circuits and to determine the corresponding Lyapunov stability and attractivity properties, topics of major importance for further dynamical analysis and control. Hemivariational inequalities are also covered in some depth relevant to application in thyristor devices. Reviews the main mathematical models applicable to the study of electrical networks involving diodes and transistors Focuses on theoretical existence and uniqueness of a solution, stability of stationary solutions, and invariance properties Provides realistic complementarity and variational problems to illustrate theoretical results Evaluates applications of the theory across many devices, including slicers, amplitude selectors, sampling gates, operational amplifiers, and four-diode bridge full-wave rectifiers Details both fully developed mathematical proofs and

common models used in electronics Provides a comprehensive literature review, including thousands of relevant references Passive Circuit Components and Electron BallisticsPassive circuit components : Resistors : Fixed and variable - Tolerance - Colour coding ; Capacitors : Fixed and variable - Dissipation factor - Characteristics and applications of various types of capacitors; Inductors : Fixed and variable - Energy stored in a magnetic field - Q factor - Mutual coupled coils.Electron ballistics : Charged particles - Force, Field intensity, potential and energy - Two dimensional motion of electron - Force in magnetic field - Motion in a magnetic field - Parallel and perpendicular electric and magnetic fields - Electrostatic deflection and Magnetic deflection in a Cathode Ray Tube - Principles and applications of CRO.Semiconductor Diodes and Special DiodesSemiconductor diodes : Classification of semiconductors - Conductivity of semiconductors - Carrier concentration in intrinsic semiconductor - Mass - Action law - Properties of intrinsic semiconductors - Variation in semiconductor parameters with temperature - Drift and diffusion currents - Carrier life time - Continuity equation - Theory of PN junction diode - Energy band structure of open circuited PN junction - Quantitative theory of PN diode currents - Diode current equation - Diode resistance - Transition or space charge capacitance - Diffusion capacitance - Effect of temperature of PN junction diodes - Junction diode switching characteristics - Breakdown in PN junction diodes - PN diode applications - Clipper - Clampers.Special diodes : Zener diode - Backward diode - Varactor diode - Step recovery diode - Point-contact diode - Tunnel diode - PIN diodes - Laser diode ; Photoconductive sensors - Photovoltaic sensors - Photoemissive sensors - Light emitters - Liquid Crystal Display (LCD) - Nixie tube - Alphanumeric displays - Optocoupler.Bipolar Junction Transistors and Field Effect TransistorsBipolar Junction Transistors : Construction - Transistor biasing - Operation of NPN transistor - Operation of PNP transistor - Types of configuration - Breakdown in transistors - Ebers-Moll model - Transistor switching times.Field Effect Transistors : Construction of N-channel JFET - Operation of N-channel JFET - Characteristic Parameters of the JFET - Expression for saturation drain current - Slope of the transfer characteristics at IDSS - Comparison of JFET and BJT - Applications of JFET - Metal oxide semiconductor field effect transistor (MOSFET) - Enhancement MOSFET - Depletion MOSFET - Comparison of MOSFET with JFET - Handling precautions for MOSFET - Comparison of N-with P-channel MOSFETs - Comparison of N-with P-Channel.Integrated Circuit FabricationIntroduction to mass technology - Manufacturing process - Construction of a bipolar transistor - Monolithic diodes - Integrated resistors - Monolithic capacitors - Inductors - Thin and thick film technology - Definition of LSI, MSI, VLSI circuits - VLSI Design rules and layout technique - Introduction to fast VLSI circuits.Metal Semiconductor Contacts and Power Control DevicesMetal semiconductor contacts : Energy band diagram of metal semiconductor junction - Schottky diode and ohmic contacts - GTO.Power control devices : PNPN diode (Shockley diode) - SCR - Thyristor ratings - LASCR (Light Activated SCR) - TRIAC - DIAC - Characteristics and equivalent circuit of UJT - Intrinsic stand-off ratio. 1. ‘Objective General English’ help in revising & preparing the concepts of English of many competitive exams 2. It is divided into four parts; 3. This book thoroughly covers the General English section asked in a number of examinations 4. Preparation booster for various competitive examinations like Bank, NDA, CDS, SSC, MBA, MCA,UPSC, B.Ed. Exams, etc Being the global language English, it has become more than necessary for you to be affluent in the English Language. Whether you are studying, Working or preparing for an examination, almost all the competitive exams today are incomplete without test of English language. Arihant’s “Objective General English” has been most preferred choice of students for preparing Objective English Questions for Competitive Examination presenting New, and

Revised edition of Objective General English, that has been designed with a new approach to fundamental concepts and changing pattern of Competitive exams. It divides the entire syllabus in 4 categories which are further segregated into Units and Chapters. Each chapter comprehensively contains short synopsis, detailed description of important rule for the concept building in grammar. Revision exercises, Exam Practice and Answers are carried after every chapter that sets a perfect idea about the question pattern and how to deal with issues arises during examination. Apart from covering all the concepts of grammar, this book exhibits tricks & techniques to solve various types of questions. TOC Part A: Foundation Module, Part B: Verbal Ability, Part C: Sequence of Sentences, Objective Comprehensive, Part D: Practical Grammar. MJ Akbar is among those who have made a significant impact on Indian society by their writing, whether as authors or editors. Founder and Editor-in-Chief of the seminal newsmagazine, Sunday, in 1976 and The Telegraph in 1982, he revolutionized Indian journalism in the 1970s and 80s. In the 1990s he launched The Asian Age, a multi-edition daily that once again had substantive impact on the profession. He has also served as the Editorial Director of India Today, Headlines Today and as the editor of the Deccan Chronicle and the Sunday Guardian. MJ, as he is popularly known, first entered public life in 1989, when he was elected to the Lok Sabha. He went back to media in 1993 and returned to the political area in 2014, when he joined the Bharatiya Janata Party (BJP) and became the party's national spokesperson during the 2014 campaign led by Prime Minister Narendra Modi. In July 2016, he was named the Minister of State for External Affairs by Prime Minister Modi. His seven books have achieved great international acclaim: India: The Siege Within; Nehru: The Making of India; Riot-after-Riot; Kashmir: Behind the Vale; The Shade of Swords: Jihad and the Conflict between Islam and Christianity, Tinderbox: The Past and Future of Pakistan and Blood Brothers, his only work of fiction. In addition, there have been four collections of his columns, reportage and essays.

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